



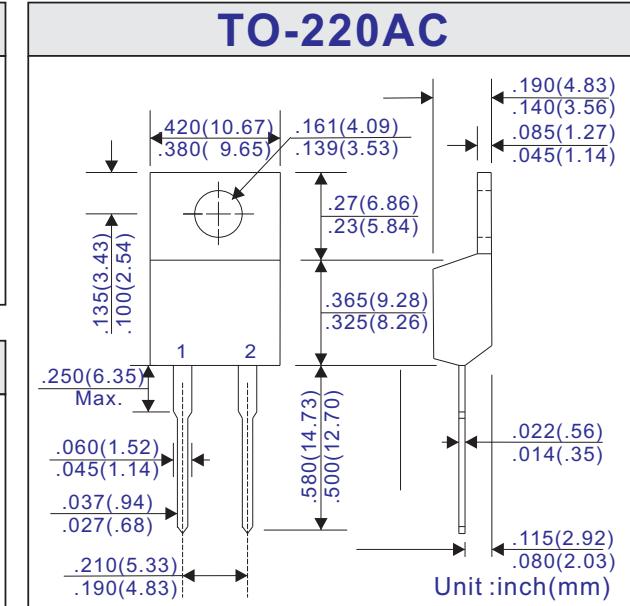
8.0A Fast Recovery Power Rectifiers - 50- 1000V

FEATURES

- Low forward drop down voltage
- Very Low reverse leakage current
- High current capability
- High reliability
- High surge current capability
- Glass passivated chip junction
- Lead free parts for green partner, meet RoHS requirements

MECHANICAL DATA

- Case: JEDEC TO-220AC molded plastic
- Epoxy: UL94-V0 rated flame retardant
- Terminals: Solderable per MIL-STD-750 Method 2026
- Polarity: As marked
- Mounting Position: Any
- Weight: 0.08 ounces, 2.24 grams
- Torque: 5 in. lbs. Max.



MAXIMUM RATING AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified

FR-	Symbols	8A01	8A02	8A03	8A04	8A05	8A06	8A07	Units
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current See Figure 1	I(AV)				8.0				Amps
Peak Forward Surge Current 8.3mS single half sine-wave superimposed on rated load (JEDEC Method)	IFSM				150.0				Amps
Maximum Instantaneous Forward Voltage at 8.0A	VF				1.3				Volts
Maximum DC Reverse Current TA= 25°C at Rated DC Blocking Voltage	IR				5.0				µA
Typical Reverse Recovery Time (Note 1)	Trr			150		250	500		nS
Typical Junction Capacitance (Note 2)	CJ			65					pF
Typical Thermal Resistance (Note 3)	R _{θJC}			2.2					°C/W
Operating Junction Temperature Range	TJ			-65 ~ +150					°C
Storage Temperature Range	TSTG			-65 ~ +150					°C

Note 1. Measured with I_F=0.5A, I_R=1A, I_{RR}=0.25A

2. Measured at 1.0MHz and applied reverse voltage of 4.0V_{dc}

3. Thermal resistance junction to case

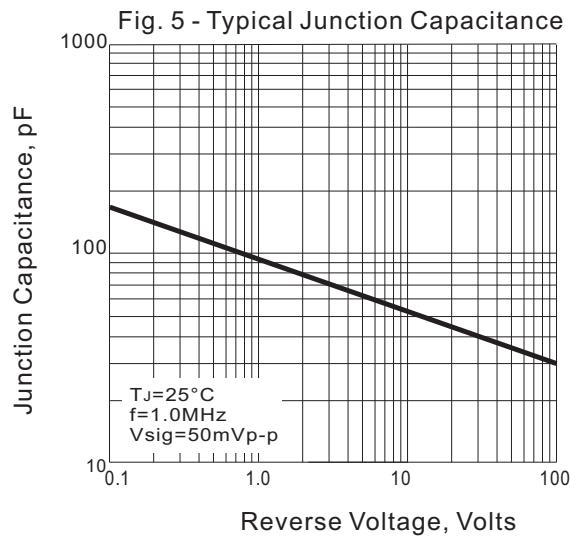
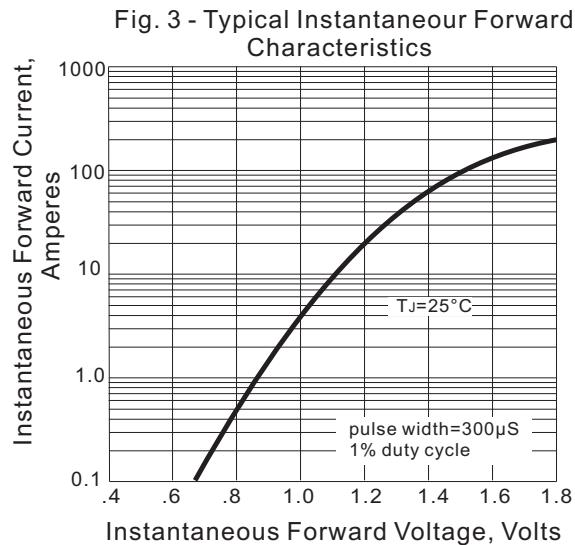
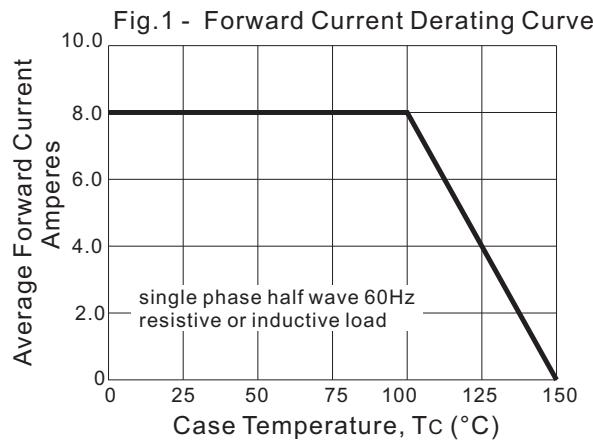


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

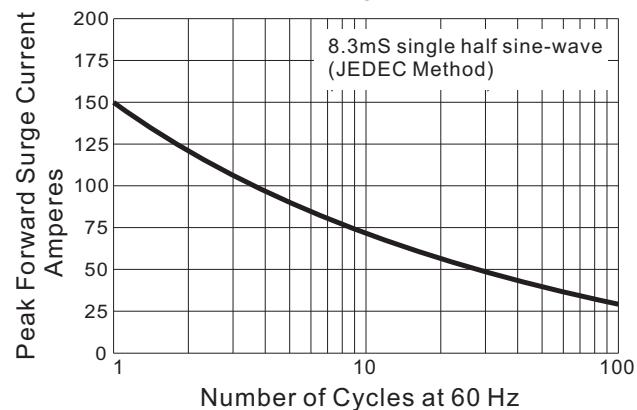


Fig. 4 - Typical Instantaneous Reverse Characteristics

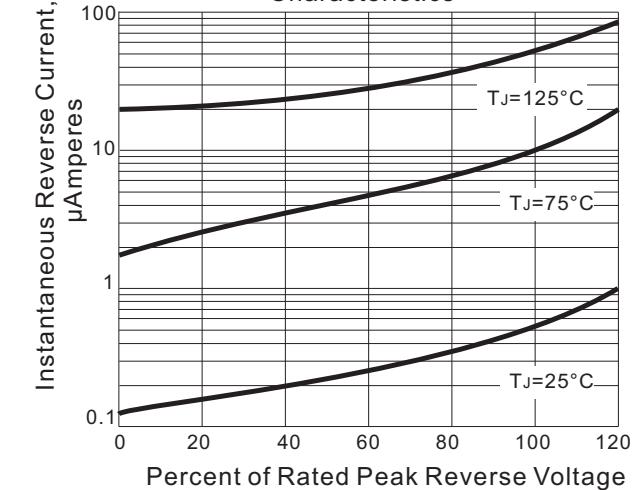
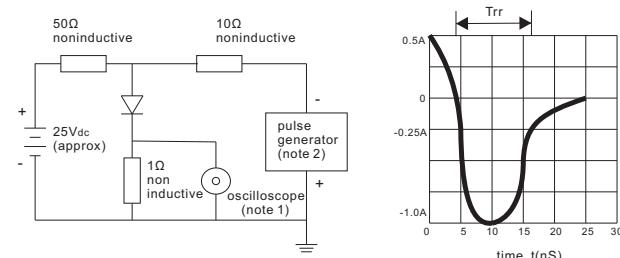


Fig. 6 - Test Circuit Diagram and Reverse Recovery Time Characteristic



Note: 1. rise time=7nS Max. input impedance=1MΩ, 22pF
2. rise time=10nS Max. source impedance=80Ω